



3TT16Z/C/J/F/A/F1

主要参数 MAIN CHARACTERISTICS

$I_{T(RMS)}$	16A
V_{DRM}	600V or 800V
I_{GT}	35mA

用途

- 交流开关
- 相位控制

产品特性

- 玻璃钝化芯片，高可靠性和一致性
- 三象限可控硅，触发电流的一致性
- 环保 RoHS 产品

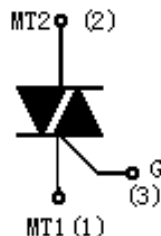
APPLICATIONS

- AC switching
- Phase control

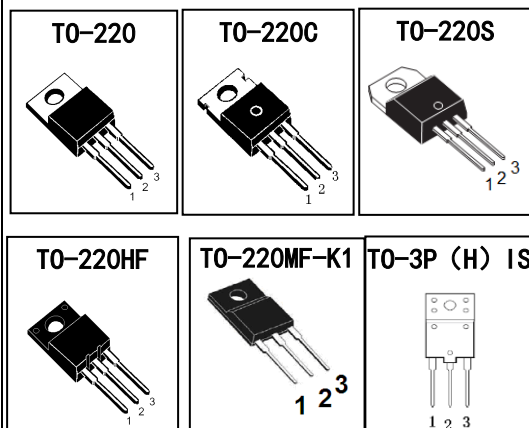
FEATURES

- Glass-passivated mesa chip for reliability and uniform
- Uniform gate trigger currents in three quadrants
- RoHS products

封装 Package



序号 Pin	引线名称 Description
1	主电极 1 MT1
2	主电极 2 MT2
3	门极 G



订货信息 ORDER MESSAGES

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装		
Halogen-Tube	Halogen-Free-Tube	Halogen-Bag	Halogen-Free-Bag		
	e		g		
3TT16Z-CA-B	3TT16Z-CA-BR	3TT16Z-CA-C	3TT16Z-CA-CR	3TT16Z	TO-220
3TT16C-C-B	3TT16C-C-BR	3TT16C-C-C	3TT16C-C-CR	3TT16C	TO-220C
3TT16J-CB-B	3TT16J-CB-BR	3TT16J-CB-C	3TT16J-CB-CR	3TT16J	TO-220S
3TT16F1-F1-B	3TT16F1-F1-BR	3TT16F1-F1-C	3TT16F1-F1-CR	3TT16F1	TO-220MF-K1
3TT16A-GA-B	3TT16A-GA-BR	N/A	N/A	3TT16A	TO-3P (H) IS

概述 GENERAL DESCRIPTION

3TT16Z/C/J/A/F1是玻璃钝化芯片结构的三象限双向晶闸管，产品在第四象限不可触发，具有较高的使用可靠性。可适用于容易出现较高dV/dt或dI/dt的交流全波控制线路中，特别推荐应用与电感性负载控制（如电机控制线路）。器件封装形式有TO-220、TO-220C、TO-220S（引线与散热片绝缘）、TO-3P（H）IS（塑料全封装）、TO-220MF-K1（塑料全封装）。

3TT16Z/C/J/A/F1 are Glass passivated three quadrant triacs, designed for high performance full-wave ac control applications where high static and dynamic dV/dt and high dI/dt can occur. They are specially recommended for use on inductive loads such as motor control circuits. Available packages are TO-220、TO-220C、TO-220S (internally isolated)、TO-3P (H) IS (plastic envelope)、TO-220MF-K1 (plastic envelope).



绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^\circ\text{C}$)

项 目 Parameter	符 号 Symbol	试 验 条 件 Condition	数 值 Value	单 位 Unit
重复峰值断态电压 Repetitive peak off-state voltage	V_{DRM}		± 600 ± 800	V
通态方均根电流 On-state RMS current	$I_{\text{T(RMS)}}$	full sine wave,	16	A
非重复浪涌峰值通态电流 Non-repetitive surge peak on-state current	I_{TSM}	full sine wave ,t=20ms	150	A
		full sine wave ,t=16.7ms	161	A
		I^2t	t=10ms	112.5
通态电流临界上升率 Repetitive rate of rise of on-state current after triggering	di/dt	$I_{\text{TM}}=20\text{A}$, $I_{\text{G}}=0.2\text{A}$, $di_{\text{G}}/dt=0.2\text{A}/\mu\text{s}$	100	$\text{A}/\mu\text{s}$
峰值门极电流 Peak gate current	I_{GM}		4	A
峰值门极电压 Peak gate voltage	V_{GM}		5	V
峰值门极功率 Peak gate power	P_{GM}		5	W
平均门极功率 Average gate power	$P_{\text{G(AV)}}$	over any 20ms period	0.5	W
存储温度 Storage temperature	T_{stg}		-40~150	$^\circ\text{C}$
操作结温 Operation junction temperature	T_{VJ}		125	$^\circ\text{C}$



电特性 ELECTRICAL CHARACTERISTIC (T_C=25°C)

项 目 Parameter	符 号 Symbol	测 试 条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit	
峰值重复断态电流 Peak Repetitive Blocking Current	I _{DRM}	V _{DM} =V _{DRM} , T _j =125°C, gate open	-	-	1.0	mA	
峰值通态电压 Peak on-state voltage	V _{TM}	I _{TM} =20A	-	1.4	1.7	V	
门极触发电流 Gate trigger current	I _{GT}	V _{DM} =12V, R _L =100 Ω	MT1(-),MT2(+),G(+)	-	-	35	mA
			MT1(-),MT2(+),G(-)	-	-	35	mA
			MT1(+),MT2(-),G(-)	-	-	35	mA
门极触发电压 Gate trigger voltage	V _{GT}	V _{DM} =12V, R _L =100 Ω	MT1(-),MT2(+),G(+)	-	0.7	1.5	V
			MT1(-),MT2(+),G(-)	-	0.7	1.5	V
			MT1(+),MT2(-),G(-)	-	0.7	1.5	V
维持电流 Holding current	I _H	V _{DM} =12V, I _{GT} =0.1A	-	-	35	mA	
擎住电流 Latching current	I _L	V _{DM} =12V, I _{GT} =0.1A	MT1(-),MT2(+),G(+)	-	-	50	mA
			MT1(-),MT2(+),G(-)	-	-	60	mA
			MT1(+),MT2(-),G(-)	-	-	50	mA
断态临界电压上升率 Rise of off- state voltage	dV/dt	V _{DM} =67% V _{DRM(MAX)} , T _j =125°C, gate open	1000	-	-	V/μs	
门极开通时间 Gate controlled turn-on time	tgt	I _{TM} =20A, V _{DM} =V _{DRM(MAX)} , I _G =0.1A, dI _G /dt=5A/μs	-	2	-	μs	

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
结到管壳的热阻 Thermal resistance junction to case	R _{th(j-c)}	full cycle(TO-220/TO-220C)			1.2	°C/W
		full cycle(TO-220S)/ TO-3P (H) IS			2.2	°C/W
		full cycle(TO-220MF-K1)			3.6	°C/W

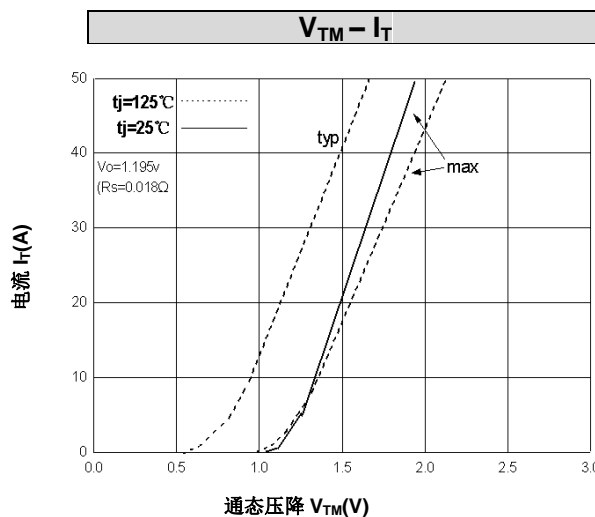
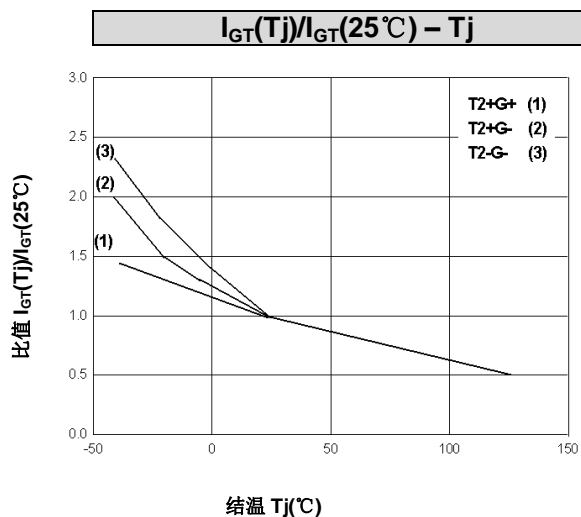
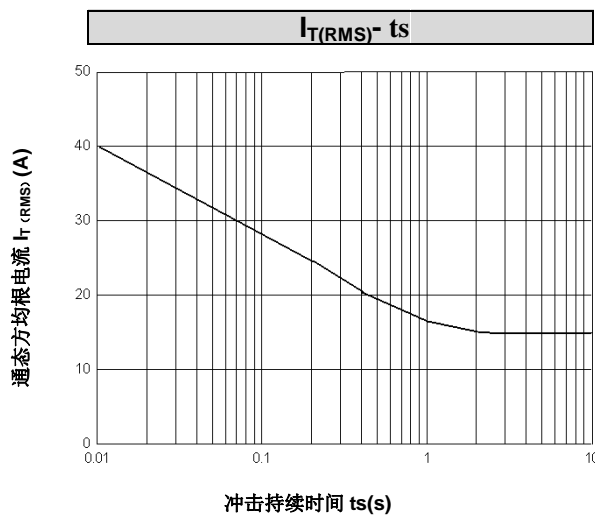
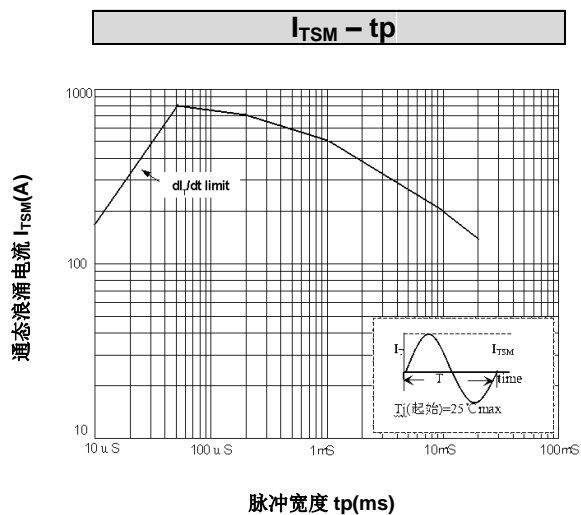
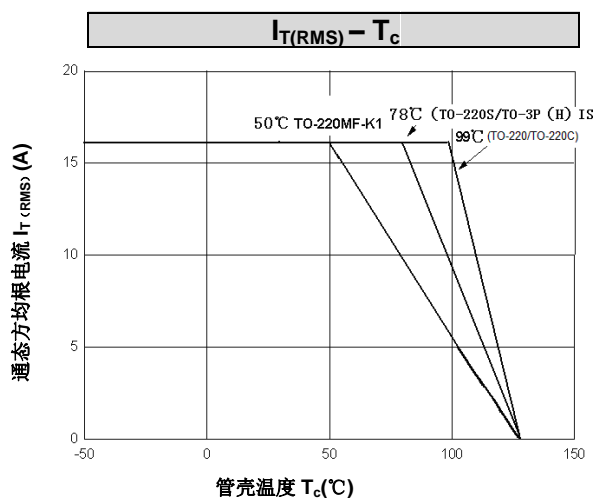
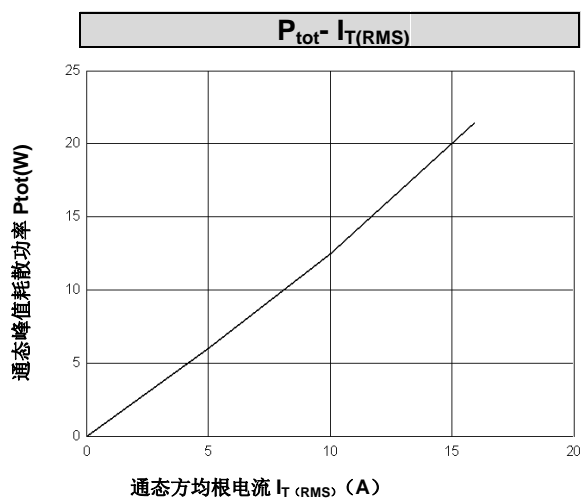
电绝缘特性 ELECTRICAL ISOLATION

项 目 Parameter	符 号 Symbol	条 件 Condition	数 值 Value	单 位 Unit
绝缘电压 Isolation voltage	V _{ISOL}	1 minute, leads to mounting tab TO-220S	2000	V
		1 minute, leads to mounting tab TO-220HF/TO-220MF-K1/ TO-3P (H) IS	2000	V





特征曲线 ELECTRICAL CHARACTERISTICS (curves)

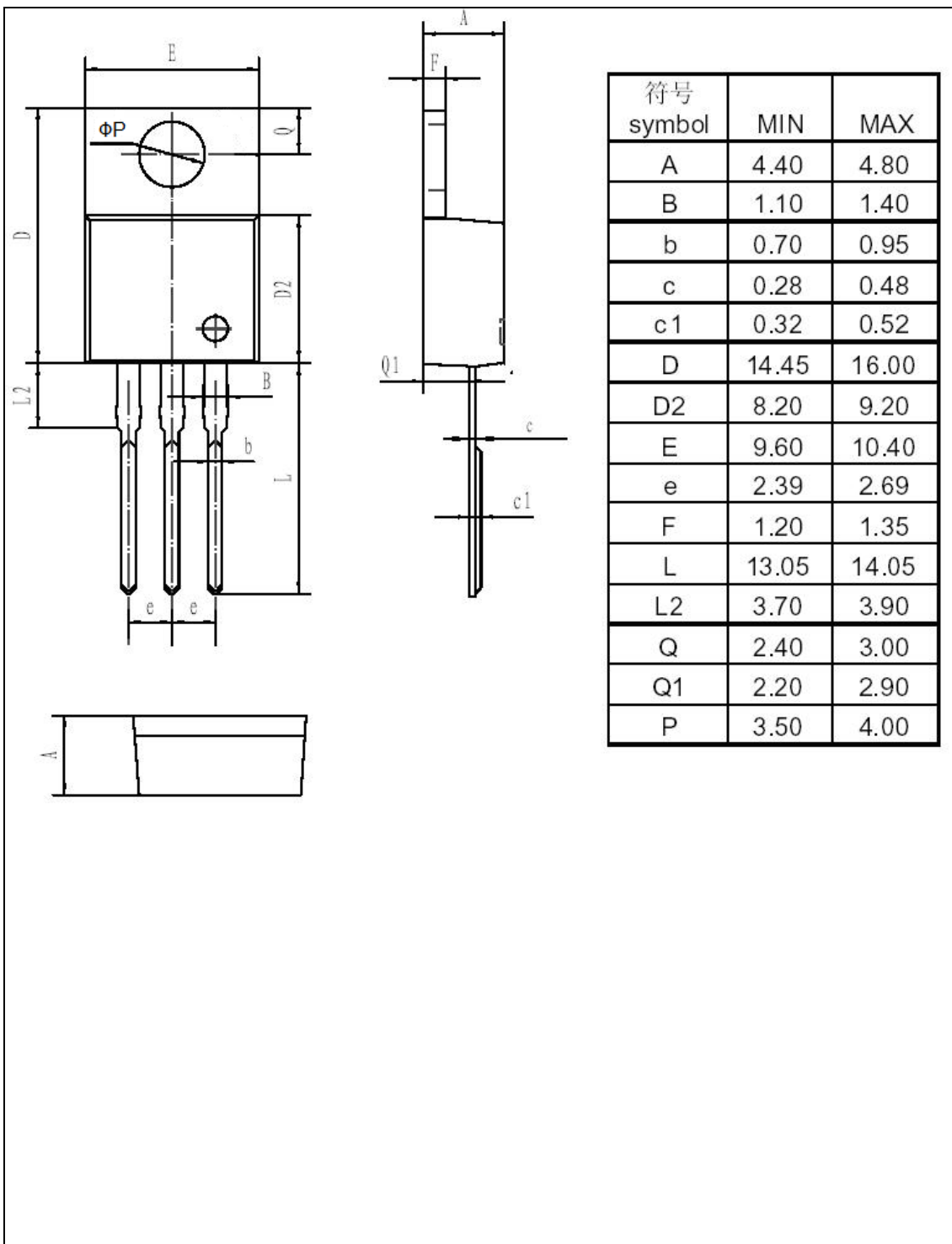




外形尺寸 PACKAGE MECHANICAL DATA

TO-220

单位 Unit : mm

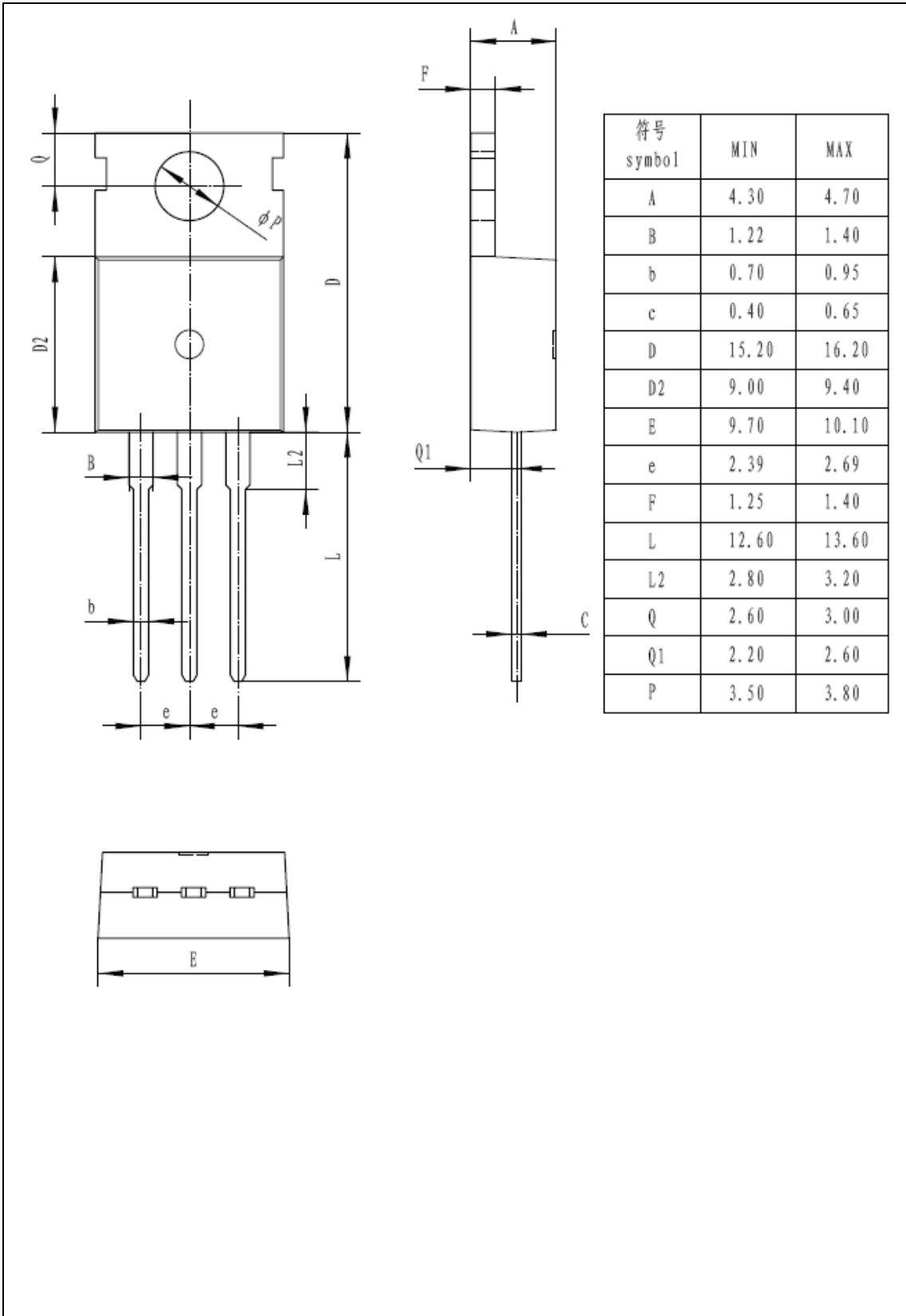




外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit : mm

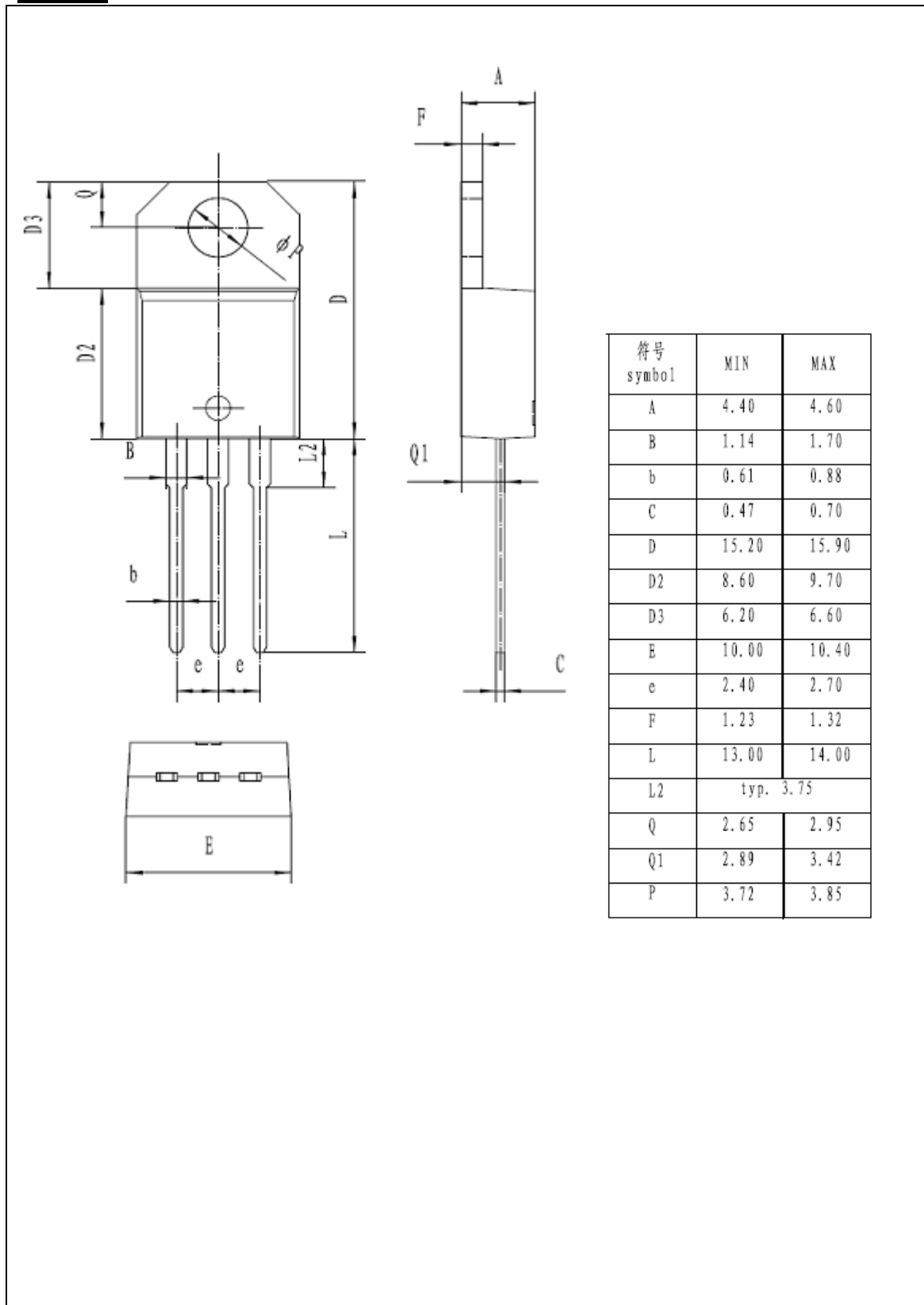




外形尺寸 PACKAGE MECHANICAL DATA

TO-220S

单位 Unit : mm

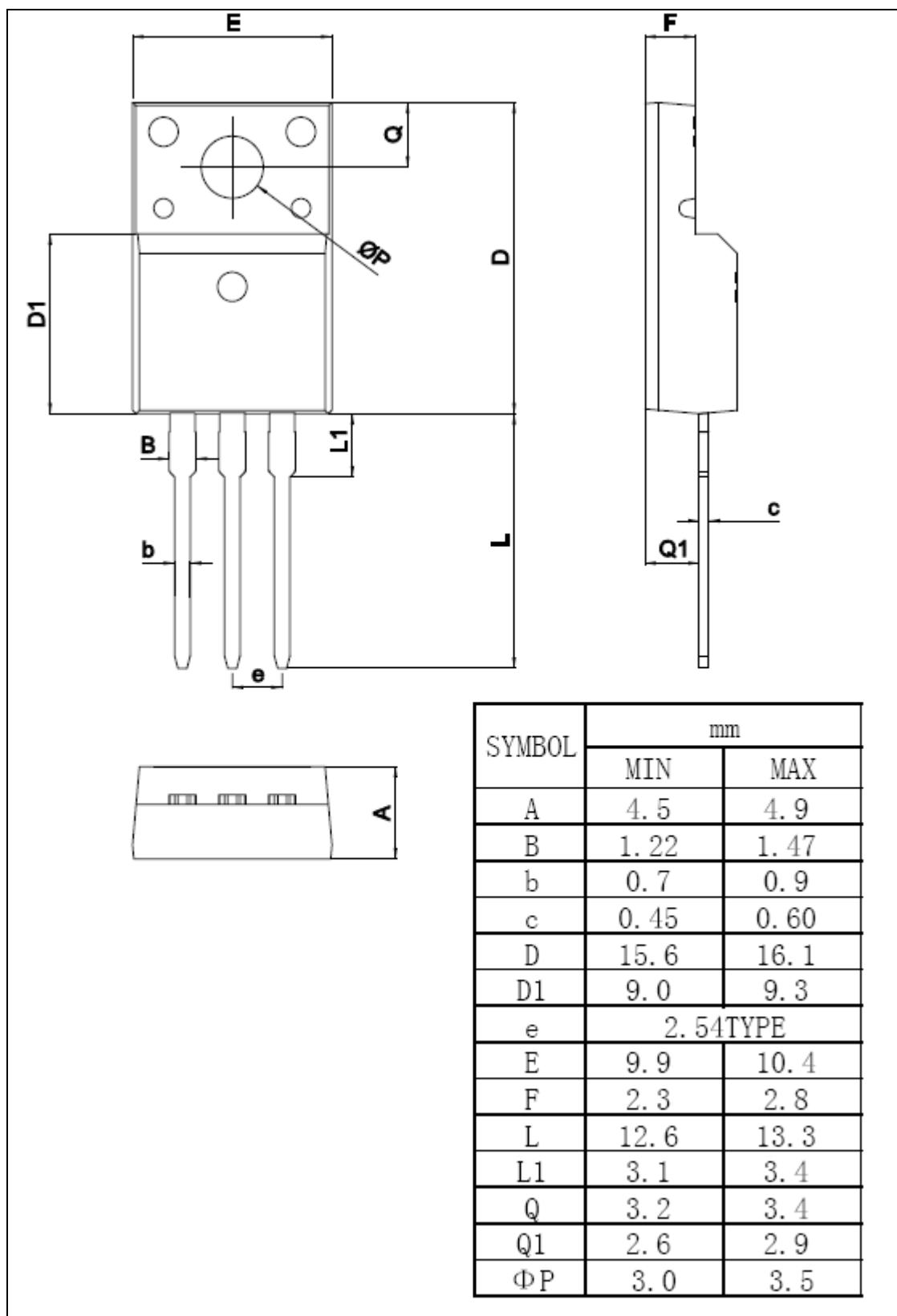




外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF-K1

单位 Unit : mm

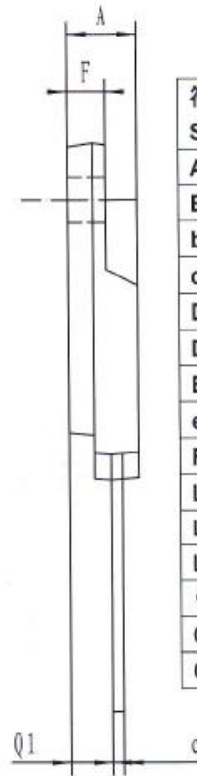
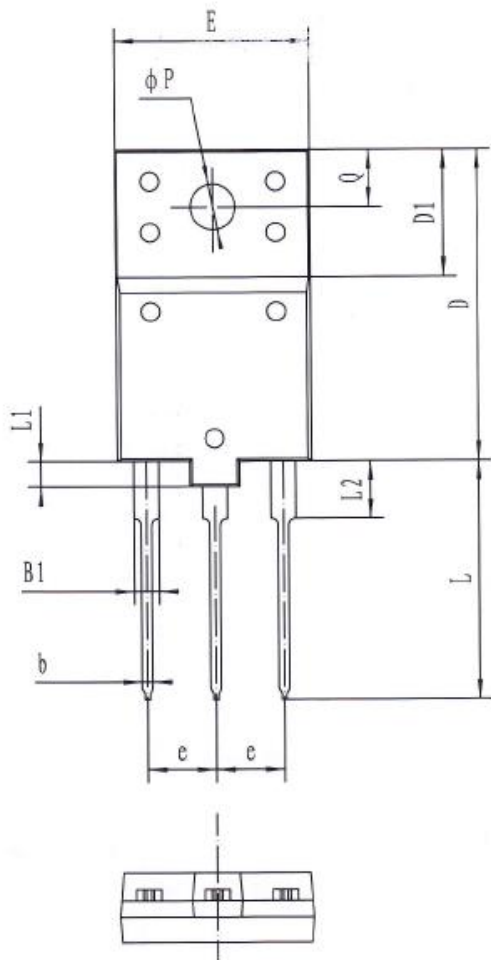




外形尺寸 PACKAGE MECHANICAL DATA

TO-3P (H) IS

单位 Unit : mm



符号 Symbol	Min	Max
A	5.2	5.8
B1	1.8	2.2
b	0.75	1.05
c	0.8	1.1
D	24.0	25.0
D1	9.8	10.2
E	15.0	16.0
e	5.45 (typ)	
F	2.7	3.3
L	18.5	19.5
L1	1.8	2.2
L2	4.3	4.7
ΦP	3.4	3.8
Q	4.3	4.7
Q1	3.1	3.5





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